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December 2014

FCD900N60Z

N-Channel SuperFET[®] II MOSFET 600 V, 4.5 A, 900 m Ω

Features

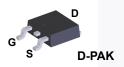
- 650 V @ T_{.1} = 150°C
- Typ. $R_{DS(on)}$ = 820 m Ω
- Ultra Low Gate Charge (Typ. Q_q = 13 nC)
- Low Effective Output Capacitance (Typ. C_{oss(eff.)} = 49 pF)
- · 100% Avalanche Tested
- · ESD Improved Capacity
- · RoHS Compliant

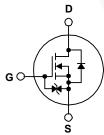
Applications

- · LCD / LED / PDP TV and Monitor Lighting
- · Solar Inverter
- Charger

Description

SuperFET® II MOSFET is Fairchild Semiconductor's brand-new high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low on-resistance and lower gate charge performance. This technology is tailored to minimize conduction loss, provide superior switching performance, dv/dt rate and higher avalanche energy. Consequently, SuperFET II MOSFET is very suitable for the switching power applications such as PFC, server/telecom power, FPD TV power, ATX power and industrial power applications.





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol		FCD900N60Z	Unit	
V _{DSS}	Drain to Source Voltage		600	V
V	Cata to Course Valtage	- DC	±20	V
V _{GSS} Gate	Gate to Source Voltage	- AC (f > 1Hz	±30	V
	Drain Current	- Continuous (T _C = 25°C)	4.5	_
ID	Diam Current	- Continuous (T _C = 100°C)	3.5	A
I _{DM}	Drain Current	- Pulsed (Note 1) 13.5	Α
E _{AS}	Single Pulsed Avalanche Energy (Note 2)		47.5	mJ
I _{AR}	Avalanche Current (Note 1)) 1	Α
E _{AR}	Repetitive Avalanche Energy	(Note 1) 0.52	mJ
dv/dt	MOSFET dv/dt		100	Mag
dv/dt	Peak Diode Recovery dv/dt	(Note 3	3) 20	V/ns
D	Davies Dissination	$(T_C = 25^{\circ}C)$	52	W
P_{D}	Power Dissipation	- Derate Above 25°C	0.42	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range		-55 to +150	°C
T _L	Maximum Lead Temperature for	Soldering, 1/8" from Case for 5 Seconds	300	οС

Thermal Characteristics

Symbol	Parameter	FCD900N60Z	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	2.4	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	100	°C/W

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FCD900N60Z	FCD900N60Z	DPAK	Tape and Reel	330 mm	16 mm	2500 units

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	cteristics					
D\/	Drain to Course Breekdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 10 \text{ mA}, T_J = 25^{\circ}\text{C}$	600	-	-	V
BV _{DSS}	Drain to Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 10 \text{ mA}, T_J = 150^{\circ}\text{C}$	650	-	-	\ \
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I _D = 10 mA, Referenced to 25°C	-	0.67	-	V/°C
BV _{DS}	Drain to Source Avalanche Breakdown Voltage	V _{GS} = 0 V, I _D = 4.5 A	-	700	-	V
	Zara Cata Valtaga Drain Current	V _{DS} = 480 V, V _{GS} = 0 V	-	-	5	
IDSS	Zero Gate Voltage Drain Current	$V_{DS} = 480 \text{ V}, T_{C} = 125^{\circ}\text{C}$	-	-	20	μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	V _{GS} = 20 V, V _{DS} = 0 V	-	-	10	uA
I _{GSSR}	Gate-Body Leakage Current, Reverse	V _{GS} = -20 V, V _{DS} = 0 V	-	-	-10	uA

On Characteristics

V _{GS(th)}	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \mu A$	2.5	-	3.5	V
R _{DS(on)}	Static Drain to Source On Resistance	$V_{GS} = 10 \text{ V}, I_D = 2.3 \text{ A}$	-	0.82	0.90	Ω
9 _{FS}	Forward Transconductance	$V_{DS} = 20 \text{ V}, I_{D} = 2.3 \text{ A}$	-	4.6	-	S

Dynamic Characteristics

C _{iss}	Input Capacitance	V - 25 V V - 0 V		543	720	pF
C _{oss}	Output Capacitance $V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V},$ $f = 1 \text{ MHz}$		-	400	530	pF
C _{rss}	Reverse Transfer Capacitance			20	30	pF
C _{oss}	Output Capacitance	V _{DS} = 380 V, V _{GS} = 0 V, f = 1 MHz	-	11	-	pF
C _{oss(eff.)}	Effective Output Capacitance	V _{DS} = 0 V to 480 V, V _{GS} = 0 V	-	49	-	pF
Q _{g(tot)}	Total Gate Charge at 10V	Fotal Gate Charge at 10V $V_{DS} = 380 \text{ V}, I_D = 2.3 \text{ A},$		13	17	nC
Q _{gs}	Gate to Source Gate Charge	V _{GS} = 10 V	-	2.3	-	nC
Q _{gd}	Gate to Drain "Miller" Charge	(Note 4)		4.8	-	nC
ESR	Equivalent Series Resistance	quivalent Series Resistance f = 1 MHz		2.4	-	Ω

Switching Characteristics

t _{d(on)}	Turn-On Delay Time		/ -	10.9	32	ns
t _r		$V_{DD} = 380 \text{ V}, I_{D} = 2.3 \text{ A},$	-	5.3	21	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, R_G = 4.7 \Omega$	-	33.6	77	ns
t _f	Turn-Off Fall Time	(Note 4)	-	11.9	34	ns

Drain-Source Diode Characteristics

I _S	Maximum Continuous Drain to Source Dioc	Maximum Continuous Drain to Source Diode Forward Current			4.5	Α
I _{SM}	Maximum Pulsed Drain to Source Diode Forward Current			// -	13.5	Α
V_{SD}	Drain to Source Diode Forward Voltage V _{GS} = 0 V, I _{SD} = 2.3 A		-	-	1.2	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _{SD} = 2.3 A,	-	156	\ -	ns
Q _{rr}	Reverse Recovery Charge $dI_F/dt = 100 \text{ A}/\mu\text{s}$		-	1.3	-	μC

Notes

- 1. Repetitive rating: pulse-width limited by maximum junction temperature.
- 2. I $_{AS}$ = 1 A, V $_{DD}$ = 50 V, R $_{G}$ = 25 Ω , starting T $_{J}$ = 25°C.
- 3. $I_{SD} \le 2.3$ A, di/dt ≤ 200 A/ μ s, $V_{DD} \le BV_{DSS}$, starting T_J = 25°C.
- 4. Essentially independent of operating temperature typical characteristics.

Typical Performance Characteristics

Figure 1. On-Region Characteristics

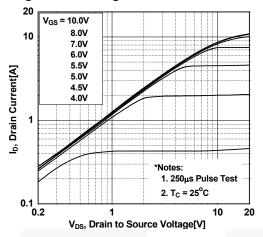


Figure 3. On-Resistance Variation vs.

Drain Current and Gate Voltage

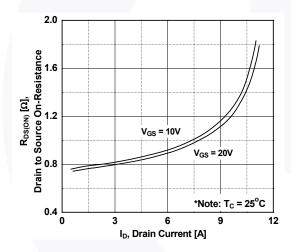


Figure 5. Capacitance Characteristics

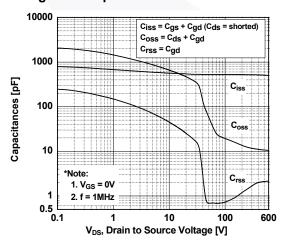


Figure 2. Transfer Characteristics

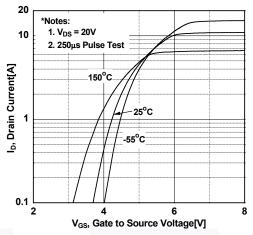


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

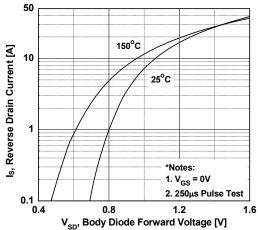
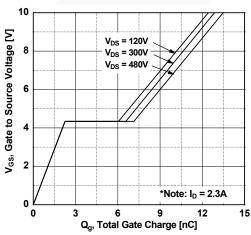


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

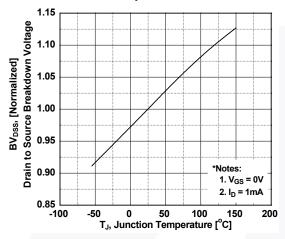


Figure 9. Maximum Safe Operating Area

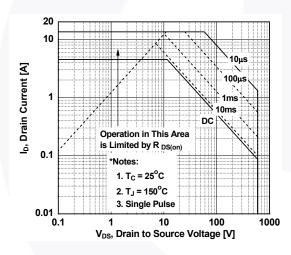


Figure 11. Eoss vs. Drain to Source Voltage

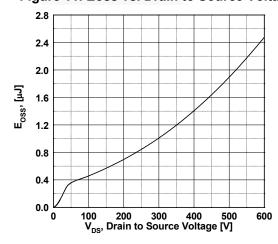


Figure 8. On-Resistance Variation vs. Temperature

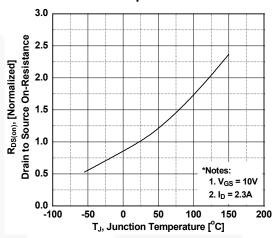
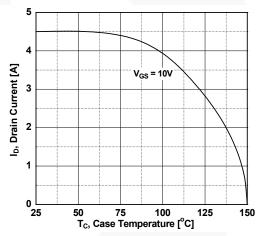
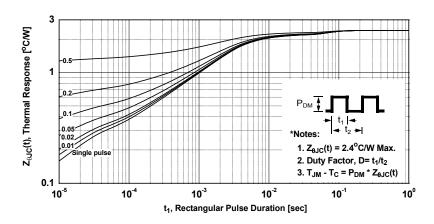


Figure 10. Maximum Drain Current vs. Case Temperature



Typical Performance Characteristics (Continued)

Figure 12. Transient Thermal Response Curve



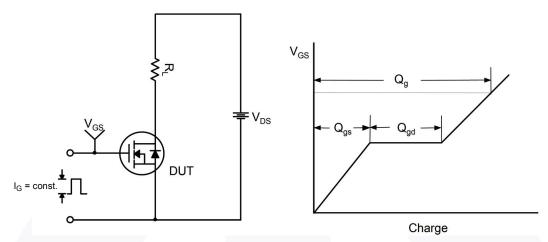


Figure 13. Gate Charge Test Circuit & Waveform

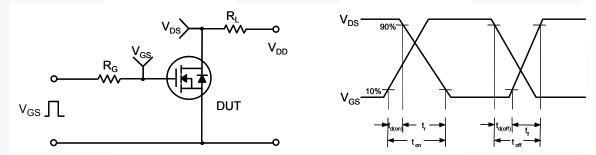


Figure 14. Resistive Switching Test Circuit & Waveforms

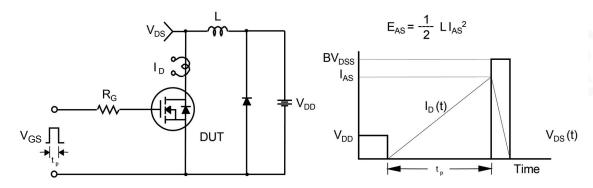


Figure 15. Unclamped Inductive Switching Test Circuit & Waveforms

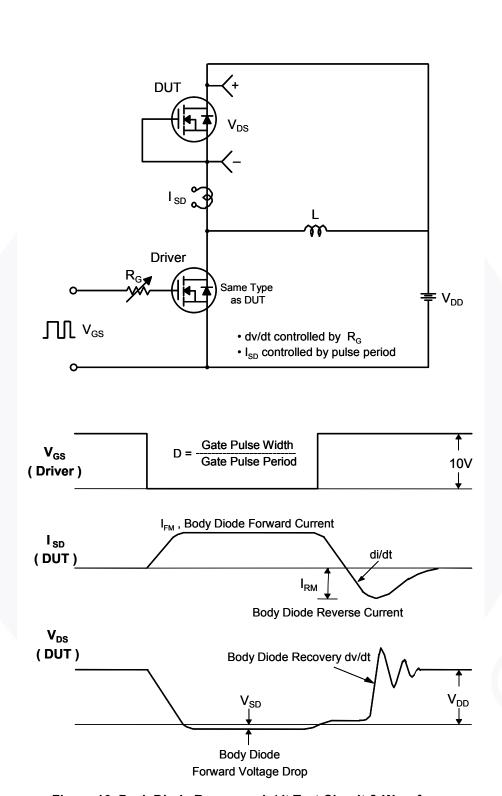


Figure 16. Peak Diode Recovery dv/dt Test Circuit & Waveforms

Mechanical Dimensions

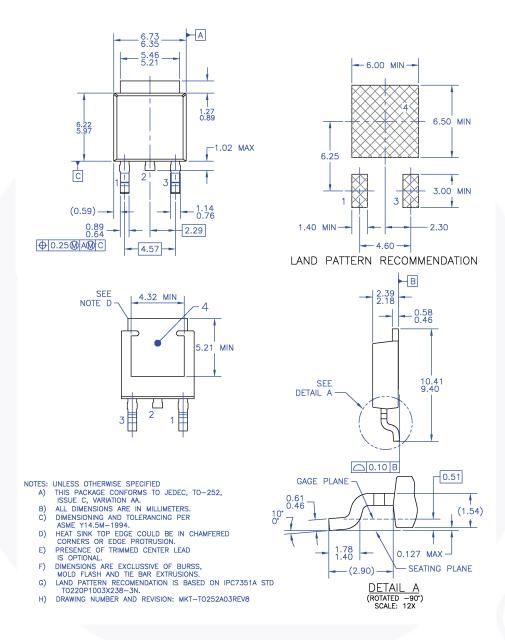


Figure 17. TO252 (D-PAK), Molded, 3-Lead, Option AA&AB

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